## Chapter Two

ELECTROSTATIC POTENTIAL AND CAPACITANCE

## Potential energy difference



- Electric potential energy difference between two points is the work required to be done by an external force in moving charge q from one point to another.

$$
\Delta U=U_{P}-U_{R}=W_{R P}
$$

## Electrostatic potential energy

- Potential energy of charge $q$ at a point is the work done by the external force in bringing the charge $q$ from infinity to that point.


## ELECTROSTATIC POTENTIAL

- The electrostatic potential (V) at any point is the work done in bringing a unit positive charge from infinity to that point.
$V=\frac{W}{q}, \mathrm{~W}-$ work done, $\mathrm{q}-$ charge .
- Also $\quad W=q V$
- It is a scalar quantity.
- Unit is J/C or volt (V)


## POTENTIAL DUE TO A POINT CHARGE



- The force acting on a unit positive charge ( +1 C ) at A , is

$$
F=\frac{1}{4 \pi \varepsilon_{0}} \frac{q \times 1}{x^{2}}=\frac{1}{4 \pi \varepsilon_{0}} \frac{q}{x^{2}}
$$

- Thus the work done to move a unit positive charge from $A$ to $B$ through a displacement $d x$ is

$$
d W=-\frac{1}{4 \pi \varepsilon_{0}} \frac{q}{x^{2}} d x
$$

- The negative sign shows that the work is done against electrostatic force.
- Thus the total work done to bring unit charge from infinity to the point $P$ is

$$
\begin{gathered}
W=\int_{\infty}^{r} d W=\int_{\infty}^{r}\left[-\frac{1}{4 \pi \varepsilon_{0}} \frac{q}{x^{2}} d x\right] \\
W=-\frac{q}{4 \pi \varepsilon_{0}} \int_{\infty}^{r}\left[\frac{1}{x^{2}} d x\right]
\end{gathered}
$$

- Integrating

$$
W=\frac{q}{4 \pi \varepsilon_{0}}\left[\frac{1}{r}-\frac{1}{\infty}\right]=\frac{q}{4 \pi \varepsilon_{0} r}
$$

- Therefore electrostatic potential is given by

$$
V=\frac{1}{4 \pi \varepsilon_{0}} \frac{q}{r}
$$

## Variation of potential V with r



POTENTIAL DUE TO AN ELECTRIC DIPOLE


The potential due to the dipole at $P$ is the sum of potentials due to the charges $q$ and $-q$

$$
V=\frac{1}{4 \pi \varepsilon_{0}}\left(\frac{q}{r_{1}}-\frac{q}{r_{2}}\right)
$$

- Using cosine law

$$
\begin{aligned}
& r_{1}^{2}=r^{2}+a^{2}-2 a r \cos \theta \\
& r_{2}^{2}=r^{2}+a^{2}+2 a r \cos \theta
\end{aligned}
$$

- For $r \gg a$

$$
r_{1}^{2}=r^{2}\left(1-\frac{2 a \cos \theta}{r}+\frac{a^{2}}{r^{2}}\right)
$$

- Neglecting the higher order terms we get

$$
r_{1}^{2} \cong r^{2}\left(1-\frac{2 a \cos \theta}{r}\right)
$$

- Similarly $r_{2}^{2} \cong r^{2}\left(1+\frac{2 a \cos \theta}{r}\right)$
- Thus $\frac{1}{r_{1}} \cong \frac{1}{r}\left(1-\frac{2 a \cos \theta}{r}\right)^{-\frac{1}{2}}$ and

$$
\frac{1}{r_{2}} \cong \frac{1}{r}\left(1+\frac{2 a \cos \theta}{r}\right)^{-\frac{1}{2}}
$$

- Using the Binomial theorem and retaining terms up to the first order in $a / r$,

$$
\begin{aligned}
& \frac{1}{r_{1}} \cong \frac{1}{r}\left(1-\frac{2 a \cos \theta}{r}\right)^{-1 / 2} \cong \frac{1}{r}\left(1+\frac{a}{r} \cos \theta\right) \\
& \frac{1}{r_{2}} \cong \frac{1}{r}\left(1+\frac{2 a \cos \theta}{r}\right)^{-1 / 2} \cong \frac{1}{r}\left(1-\frac{a}{r} \cos \theta\right)
\end{aligned}
$$

- Thus the potential is

$$
V=\frac{q}{4 \pi \varepsilon_{0}} \frac{2 a \cos \theta}{r^{2}}
$$

- Using $\mathrm{p}=\mathrm{q} \times 2 \mathrm{a}$, we get

$$
V=\frac{1}{4 \pi \varepsilon_{0}} \frac{p \cos \theta}{r^{2}}
$$

## Special cases

- Potential at point on the axial line

At the axial point $\theta=0$, therefore

$$
V=\frac{1}{4 \pi \varepsilon_{0}} \frac{p}{r^{2}}
$$

- Potential at point on the equatorial line

At the equatorial line $\theta=90^{\circ}$, thus, $\mathrm{V}=0$.

## POTENTIAL DUE TO A SYSTEM OF CHARGES

- By the superposition principle, the potential at a point due to a system of charges is the algebraic sum of the potentials due to the individual charges.

- Thus $V=V_{1}+V_{2}+\ldots \ldots . . V_{n}$

$$
=\frac{1}{4 \pi \varepsilon_{0}}\left(\frac{q_{1}}{r_{1 \mathrm{P}}}+\frac{q_{2}}{r_{2 \mathrm{P}}}+\ldots \ldots+\frac{q_{n}}{r_{n \mathrm{P}}}\right)
$$

Potential due to a uniformly charged spherical shell

- For a uniformly charged spherical shell, the electric field outside the shell is as if the entire charge is concentrated at the centre
- Thus potential at a distance $r$, from the shell is

$$
V=\frac{1}{4 \pi \varepsilon_{0}} \frac{q}{r}
$$

- Where $r \geq R$, radius of the shell
- Inside the shell, the potential is a constant and has the same value as on its surface.

$$
V=\frac{1}{4 \pi \varepsilon_{0}} \frac{q}{R}
$$

## Equipotential surface

- Surface with constant value of potential at all points on the surface.


## Properties of Equipotential surface

- Work done to move a charge on an equipotential surface is zero.
- Electric field is perpendicular to the surface.
- Two equipotential surfaces never intersect.


## Equipotential surface of a single charge

## Equipotential surfaces for a uniform electric field



Equipotential surfaces for a dipole


Equipotential surfaces for two identical positive charges


Relation between electric field and potential


- The work done to move a unit positive charge from $B$ to $A$ is

$$
\text { Work }=E d r
$$

- This work equals the potential difference $V_{A}-V_{B}$.
- Thus $E d r=V-(V+d V)=-d V$
- That is $E=-\frac{d V}{d r}$


## POTENTIAL ENERGY OF A SYSTEM OF CHARGES

## For a system of two charges



- As there is no external field work done in bringing $q_{1}$ from infinity to $r_{1}$ is zero.
- The potential due to the charge $q_{1}$ is

$$
V_{1}=\frac{1}{4 \pi \varepsilon_{\mathrm{O}}} \frac{q_{1}}{r_{1 \mathrm{P}}}
$$

- The work done in bringing charge $q_{2}$ from infinity to the point $\mathbf{r}_{2}$ is

$$
\text { work done on } q_{2}=\frac{1}{4 \pi \varepsilon_{0}} \frac{q_{1} q_{2}}{r_{12}}
$$

- This work gets stored in the form of potential energy of the system.
- Thus, the potential energy of a system of two charges $q_{1}$ and $q_{2}$ is

$$
U=\frac{1}{4 \pi \varepsilon_{0}} \frac{q_{1} q_{2}}{r_{12}}
$$

## For a system of three charges



- The work done to bring $q_{1}$ from infinity to the point is zero.
- The work done to bring $\mathrm{q}_{2}$ is

$$
q_{2} V_{1}\left(\mathbf{r}_{2}\right)=\frac{1}{4 \pi \varepsilon_{0}} \frac{q_{1} q_{2}}{r_{12}}
$$

- The charges $q_{1}$ and $q_{2}$ produce a potential, which at any point $P$ is given by

$$
V_{1,2}=\frac{1}{4 \pi \varepsilon_{0}}\left(\frac{q_{1}}{r_{1 \mathrm{P}}}+\frac{q_{2}}{r_{2 \mathrm{P}}}\right)
$$

- Work done in bringing $q_{3}$ from infinity to the point $r_{3}$ is

$$
q_{3} V_{1.2}\left(\mathbf{r}_{3}\right)=\frac{1}{4 \pi \varepsilon_{0}}\left(\frac{q_{1} q_{3}}{r_{13}}+\frac{q_{2} q_{3}}{r_{23}}\right)
$$

- The total work done in assembling the charges

$$
U=\frac{1}{4 \pi \varepsilon_{0}}\left(\frac{q_{1} q_{2}}{r_{12}}+\frac{q_{1} q_{3}}{r_{13}}+\frac{q_{2} q_{3}}{r_{23}}\right)
$$

## POTENTIAL ENERGY IN AN EXTERNAL FIELD

## Potential energy of a single charge

- Potential energy of $q$ at $r$ in an external field is

$$
U=q V(r)
$$

- where $V(r)$ is the external potential at the point $r$.


## Potential energy of a system of two charges in an external field

- Work done to bring q1 is

$$
q_{1} V\left(\mathbf{r}_{1}\right)
$$

- Work done on q2 against the external field

$$
=q_{2} V\left(\mathbf{r}_{2}\right)
$$

- Work done on q2 against the field due to q1
- In the static situation, the free charges have so distributed themselves that the electric field is zero everywhere inside
- At the surface electric field is normal.
- If E were not normal to the surface, it would have some non-zero component along the surface.
- Free charges on the surface of the conductor would then experience force and move.
- In the static situation, therefore, E should have no tangential component.
- The interior of a conductor can have no excess charge in the static situation
- A neutral conductor has equal amounts of positive and negative charges in every small volume or surface element.
- When the conductor is charged, the excess charge can reside only on the surface in the static situation.
- Electric potential is constant throughout the volume of the conductor.
- Since $\mathbf{E}=0$ inside the conductor and has no tangential component on the surface, no work is done in moving a small test charge within the conductor and on its surface.
- That is, there is no potential difference between any two points inside or on the surface of the conductor.
- Electric field at the surface of a charged conductor

$$
\mathbf{E}=\frac{\sigma}{\varepsilon_{\mathbf{o}}} \hat{\mathbf{n}}
$$

- where $\sigma$ is the surface charge density and $n \mathrm{n}$ is a unit vector normal to the surface in the outward direction


## Derivation



- choose a pill box (a short cylinder) as the Gaussian surface about any point $P$ on the surface.
- The pill box is partly inside and partly outside the surface of the conductor.
- It has a small area of cross section $\delta S$ and negligible height.
- The contribution to the total flux through the pill box comes only from the outside (circular) cross-section of the pill box.
- The charge enclosed by the pill box is $\sigma \delta S$.
- By Gauss's law

$$
\begin{aligned}
& E \delta S=\frac{|\sigma| \delta S}{\varepsilon_{\mathrm{o}}} \\
& E=\frac{|\sigma|}{\varepsilon_{\mathrm{o}}}
\end{aligned}
$$

## Electrostatic shielding



- The vanishing of electric field inside a charged conducting cavity is known as electrostatic shielding.
- The effect can be made use of in protecting sensitive instruments from outside electrical influence.
- Why it is safer to be inside a car during lightning?
- Due to Electrostatic shielding, $\mathrm{E}=0$ inside the car.


## DIELECTRICS

- Dielectrics are non-conducting substances.
- They have no (or negligible number of ) charge carriers.


## Conductor in an external field

- In an external field the free charge carriers in the conductor move and an electric field which is equal and opposite to the external field is induced inside the conductor.
- The two fields cancel each other and the net electrostatic field in the conductor is zero.



## Dielectric in an external field

- In a dielectric, the external field induces dipole moment by stretching or reorienting molecules of the dielectric.
- Thus a net electric field is induced inside the dielectric in the opposite direction.
- The induced field does not cancel the external field.

- Dielectric substances may be made of polar or non polar molecules.


## Non polar molecule in an external field



- In an external electric field, the positive and negative charges of a nonpolar molecule are displaced in opposite directions.
- The non-polar molecule thus develops an induced dipole moment.


## Linear isotropic dielectrics

- When a dielectric substance is placed in an electric field, a net dipole moment is induced in it.
- When the induced dipole moment is in the direction of the field and is proportional to the field strength the substances are called linear isotropic dielectrics.


## Polar molecule in external field



- In the absence of any external field, the different permanent dipoles are oriented randomly due to thermal agitation; so the total dipole moment is zero.
- When an external field is applied, the individual dipole moments tend to align with the field.
- A dielectric with polar molecules also develops a net dipole moment in an external field.


## Polarisation

- The dipole moment per unit volume is called polarisation and is denoted by $\boldsymbol{P}$.
- For linear isotropic dielectrics,

$$
\mathbf{P}=\chi_{e} \mathbf{E}
$$

- where $\chi_{\mathrm{e}}$ is the electric susceptibility of the dielectric medium.


## A rectangular dielectric slab placed in a uniform

 external field

- The polarised dielectric is equivalent to two charged surfaces with induced surface charge densities, say $\sigma_{p}$ and $-\sigma_{p}$
- That is a uniformly polarised dielectric amounts to induced surface charge density, but no volume charge density.


## Capacitor

- It is a charge storing device.
- A capacitor is a system of two conductors separated by an insulator.

- A capacitor with large capacitance can hold large amount of charge $Q$ at a relatively small V.


## Capacitance

- The potential difference is proportional to the charge, Q .
- Thus $C=\frac{Q}{V}$
- The constant C is called the capacitance of the capacitor. $C$ is independent of $Q$ or $V$.
- The capacitance C depends only on the geometrical configuration (shape, size, separation) of the system of two conductors
- SI unit of capacitance is farad.
- Other units are, $1 \mu \mathrm{~F}=10^{-6} \mathrm{~F}, 1 \mathrm{nF}=10^{-9} \mathrm{~F}$, $1 \mathrm{pF}=10^{-12} \mathrm{~F}$, etc.


## Symbol of capacitor

Fixed capacitance


## Variable capacitance



## Dielectric strength

- The maximum electric field that a dielectric medium can withstand without break-down is called its dielectric strength.
- The dielectric strength of air is about $3 \times 10^{6} \mathrm{Vm}^{-1}$.


## THE PARALLEL PLATE CAPACITOR

- A parallel plate capacitor consists of two large plane parallel conducting plates separated by a small distance


## Capacitance of parallel plate capacitor

- Let $A$ be the area of each plate and $d$ the separation between them.
- The two plates have charges $Q$ and $-Q$.
- Plate 1 has surface charge density $\sigma=Q / A$ and plate 2 has a surface charge density $-\sigma$.

- At the region I and II, E=0

$$
E=\frac{\sigma}{2 \varepsilon_{0}}-\frac{\sigma}{2 \varepsilon_{0}}=0
$$

- At the inner region

$$
E=\frac{\sigma}{2 \varepsilon_{0}}+\frac{\sigma}{2 \varepsilon_{0}}=\frac{\sigma}{\varepsilon_{0}}=\frac{\Theta}{\varepsilon_{0} A}
$$

- The direction of electric field is from the positive to the negative plate.
- For a uniform electric field the potential difference is

$$
V=E d=\frac{1}{\varepsilon_{0}} \frac{\varrho d}{A}
$$

- The capacitance C of the parallel plate capacitor is then

$$
C=\frac{Q}{V}==\frac{\varepsilon_{0} A}{d}
$$

- Thus $C=\frac{\varepsilon_{0} A}{d}$


## Effect of dielectric on capacitance

- When dielectric medium is placed capacitance increases.
- When there is vacuum between the plates,

$$
E_{0}=\frac{\sigma}{\varepsilon_{0}} \quad V_{0}=E_{0} d
$$

- The capacitance $C_{0}$ in this case is

$$
C_{\mathrm{o}}=\frac{Q}{V_{\mathrm{o}}}=\varepsilon_{\mathrm{o}} \frac{A}{d}
$$

- When a dielectric is introduced

$$
E=\frac{\sigma-\sigma_{P}}{\varepsilon_{0}}
$$

- so that the potential difference across the plates is

$$
V=E d=\frac{\sigma-\sigma_{P}}{\varepsilon_{0}} d
$$

- For linear dielectrics, $\sigma_{p}$ is proportional to $E_{0}$, and hence to $\sigma$.
- Thus, $\left(\sigma-\sigma_{p}\right)$ is proportional to $\sigma$ and we can write

$$
\sigma-\sigma_{P}=\frac{\sigma}{K}
$$

- where $K$ is the dielectric constant.
- Thus

$$
V=\frac{\sigma d}{\varepsilon_{0} K}=\frac{\Omega d}{A \varepsilon_{0} K}
$$

- The capacitance $C$, with dielectric between the plates, is then

$$
C=\frac{\Theta}{V}=\frac{\varepsilon_{\mathrm{O}} K A}{d}
$$

- That is

$$
C=\frac{\varepsilon_{0} K A}{d}
$$

- The product $\varepsilon_{0} K$ is called the permittivity of the medium and is denoted by $\varepsilon$.

$$
\varepsilon=\varepsilon_{0} \check{K}
$$

- For vacuum $K=1$ and $\varepsilon=\varepsilon_{0} ; \varepsilon_{0}$ is called the permittivity of the vacuum.
- Thus the dielectric constant of the substance is

$$
K=\frac{\varepsilon}{\varepsilon_{0}}
$$

- Also

$$
K=\frac{C}{C_{\mathrm{o}}}
$$

- $\mathrm{C}_{0}$ - capacitance in vacuum, C - capacitance in dielectric medium.


## Combination of capacitors

## Capacitors in series



- In series charge is same and potential is different on each capacitors.
- The total potential drop $V$ across the combination is

$$
V=V_{1}+V_{2}
$$

- Considering the combination as an effective capacitor with charge $Q$ and potential difference $V$, we get

$$
\frac{Q}{C}=\frac{Q}{C_{1}}+\frac{Q}{C_{2}}
$$

- Therefore effective capacitance is

$$
\frac{1}{C}=\frac{1}{C_{1}}+\frac{1}{C_{2}}
$$

- For n capacitors in series

$$
\frac{1}{C}=\frac{1}{C_{1}}+\frac{1}{C_{2}}+\ldots \ldots .+\frac{1}{C_{n}}
$$

## Capacitors in parallel



- In parallel the charge is different, potential is same on each capacitor.
- The charge on the equivalent capacitor is

$$
Q=Q_{1}+Q_{2}
$$

- Thus $C V=C_{1} V+C_{2} V$
- Therefore $C=C_{1}+C_{2}$
- In general , for n capacitors

$$
C=C_{1}+C_{2}+\ldots \ldots \ldots \ldots . . .+C_{n}
$$

## Energy stored in a capacitor

- Energy stored in a capacitor is the electric potential energy.
(a)

(b)
- Charges are transferred from conductor 2 to conductor 1 bit by bit, so that at the end, conductor 1 gets charge $Q$.
- Work done to move a charge dq from conductor 2 to conductor 1 , is $d W=$ Potential $\times C h \arg e$
- That is $d W=\frac{q}{C} \times d q$
- Since potential at conductor 1 is , $\mathbf{q} / \mathbf{C}$.
- Thus the total work done to attain a charge $Q$ on conductor 1 , is

$$
W=\int_{0}^{Q} d W=\int_{0}^{Q} \frac{q}{C} \times d q
$$

- On integration we get,

$$
W=\frac{1}{C}\left[\frac{q^{2}}{2}\right]_{0}^{Q}=\frac{Q^{2}}{2 C}
$$

- This work is stored in the form of potential energy of the system.
- Thus energy stored in the capacitor is

$$
U=\frac{Q^{2}}{2 C}
$$

- Also $U=\frac{1}{2} Q V$ or $U=\frac{1}{2} C V^{2}$


## Alternate method

- We have the $\mathrm{Q}-\mathrm{V}$ graph of a capacitor,

- Energy = area under the graph
- Thus, $U=\frac{1}{2} \times Q \times V$
- Also $U=\frac{1}{2} C V^{2}$


## Energy Density of a capacitor

- Energy density is the energy stored per unit volume.
- We have $U=\frac{Q^{2}}{2 C}$
- But $Q=\sigma A$ and $C=\frac{\varepsilon_{0} A}{d}$
- Thus we get $U=\frac{(\sigma A)^{2}}{2}\left(\frac{d}{\varepsilon_{0} A}\right)$
- Using $E=\frac{\sigma}{\varepsilon_{0}}$, we get

$$
U=\frac{1}{2} \varepsilon_{0} E^{2} \times A d
$$

- Thus energy per unit volume is given by

$$
\frac{U}{A d}=\frac{1}{2} \varepsilon_{0} E^{2}
$$

- That is the energy density of the capacitor is

$$
u=\frac{1}{2} \varepsilon_{0} E^{2}
$$

## VAN DE GRAAFF GENERATOR

## Uses

- Used to generate high potential about million volts and electric field close to $3 \times 10^{6} \mathrm{~V} / \mathrm{m}$.
- High potential generated is used to accelerate charged particles to high energies.


## Principle

- When a small conducting sphere is kept inside a large sphere, potential is high at the small sphere.

- Potential due to small sphere of radius $r$ carrying charge $q$

$$
\begin{aligned}
& =\frac{1}{4 \pi \varepsilon_{0}} \frac{q}{r} \text { at surface of small sphere } \\
& =\frac{1}{4 \pi \varepsilon_{0}} \frac{q}{R} \text { at large shell of radius } R .
\end{aligned}
$$

- Taking both charges $q$ and $Q$, we have

$$
\begin{aligned}
& V(R)=\frac{1}{4 \pi \varepsilon_{0}}\left(\frac{Q}{R}+\frac{q}{R}\right) \\
& V(r)=\frac{1}{4 \pi \varepsilon_{0}}\left(\frac{G}{R}+\frac{q}{r}\right) \\
& V(r)-V(R)=\frac{q}{4 \pi \varepsilon_{0}}\left(\frac{1}{r}-\frac{1}{R}\right)
\end{aligned}
$$

- Thus the potential at the smaller sphere is higher than the larger sphere.


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- If the two spheres are connected with a wire, charge will flow from smaller sphere to larger one.


## Construction



- A large spherical conducting shell is supported at a height several meters above the ground on an insulating column.
- A long narrow endless belt insulating material, like rubber or silk, is wound around two pulleys - one at ground level, one at the centre of the shell.


## Working

- The belt is kept continuously moving by a motor driving the lower pulley.
- It continuously carries positive charge, sprayed on to it by a brush at ground level, to the top.
- At the top, the belt transfers its positive charge to another conducting brush connected to the large shell.
- Thus positive charge is transferred to the shell, where it spreads out uniformly on the outer surface.
- In this way, voltage differences of as much as 6 or $\mathbf{8}$ million volts (with respect to ground) can be built up.
- The voltage produced by an open-air Van de Graaff machine is limited by corona discharge to about 5 megavolts.
- Most modern industrial machines are enclosed in a pressurized tank of insulating gas these can achieve potentials of as much as about 25 megavolts.

